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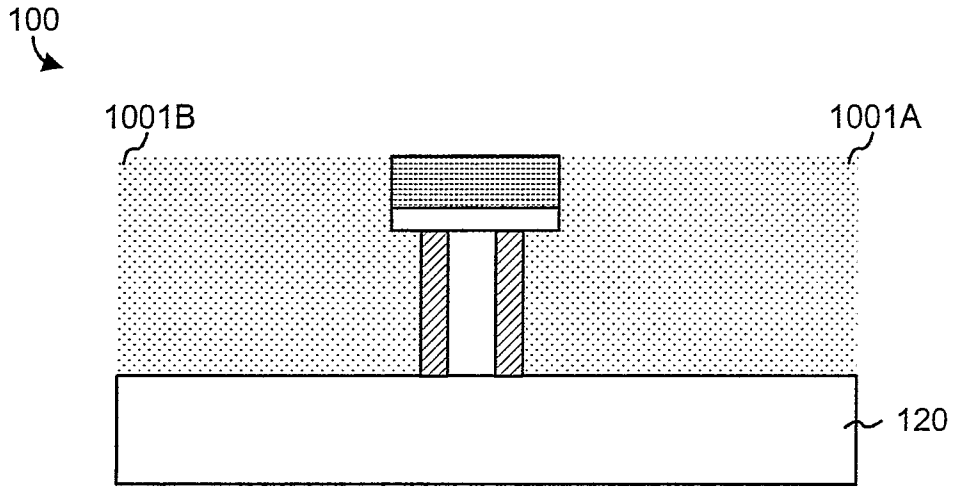
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(54) Title: NARROW FIN FINFET



(57) Abstract: A narrow channel FinFET is described herein with a channel width of less than 6 nm. The FinFET may include a fin (140) in which the channel area is trimmed using a NH_4OH etch or a reactive ion etch (RIE).

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